

勝特力材料 886-3-5753170  
 勝特力电子(上海) 86-21-54151736  
 勝特力电子(深圳) 86-755-83298787  
 Http://www.100y.com.tw

# International **IR** Rectifier

Data Sheet No.PD60217 Rev A

## IR2011(S) & (PbF)

### HIGH AND LOW SIDE DRIVER

#### Features

- Floating channel designed for bootstrap operation  
 Fully operational up to +200V  
 Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10V to 20V
- Independent low and high side channels
- Input logic HIN/LIN active high
- Undervoltage lockout for both channels
- 3.3V and 5V input logic compatible
- CMOS Schmitt-triggered inputs with pull-down
- Matched propagation delay for both channels
- 8-Lead SOIC is also available LEAD-FREE (PbF)

#### Applications

- Audio Class D amplifiers
- High power DC-DC SMPS converters
- Other high frequency applications

#### Description

The IR2011 is a high power, high speed power MOSFET driver with independent high and low side referenced output channels, ideal for Audio Class D and DC-DC converter applications. Logic inputs are compatible with standard CMOS or LSTTL output, down to 3.0V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET in the high side configuration which operates up to 200 volts. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction.

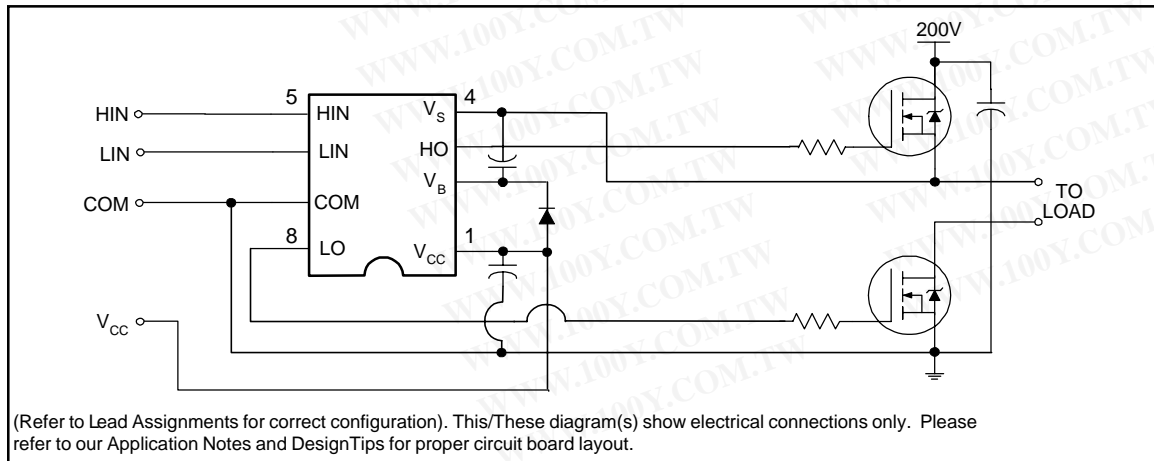
#### Product Summary

$V_{\text{OFFSET}}$	200V max.
$I_{\text{O+/-}}$	1.0A /1.0A typ.
$V_{\text{OUT}}$	10 - 20V
$t_{\text{on/off}}$	80 & 60 ns typ.
Delay Matching	20 ns max.

#### Packages



#### Typical Connection



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### Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units	
V <sub>B</sub>	High side floating supply voltage	-0.3	250	V	
V <sub>S</sub>	High side floating supply offset voltage	V <sub>B</sub> - 25	V <sub>B</sub> + 0.3		
V <sub>HO</sub>	High side floating output voltage	V <sub>S</sub> - 0.3	V <sub>B</sub> + 0.3		
V <sub>CC</sub>	Low side fixed supply voltage	-0.3	25		
V <sub>LO</sub>	Low side output voltage	-0.3	V <sub>CC</sub> + 0.3		
V <sub>IN</sub>	Logic input voltage (HIN & LIN)	COM - 0.3	V <sub>CC</sub> + 0.3		
dV <sub>S</sub> /dt	Allowable offset supply voltage transient (figure 2)	—	50	V/ns	
P <sub>D</sub>	Package power dissipation @ T <sub>A</sub> ≤ +25°C	(8-lead DIP)	—	1.0	W
		(8-lead SOIC)	—	0.625	
R <sub>THJA</sub>	Thermal resistance, junction to ambient	(8-lead DIP)	—	125	°C/W
		(8-lead SOIC)	—	200	
T <sub>J</sub>	Junction temperature	—	150	°C	
T <sub>S</sub>	Storage temperature	-55	150		
T <sub>L</sub>	Lead temperature (soldering, 10 seconds)	—	300		

### Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions. The V<sub>S</sub> and COM offset ratings are tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
V <sub>B</sub>	High side floating supply absolute voltage	V <sub>S</sub> + 10	V <sub>S</sub> + 20	V
V <sub>S</sub>	High side floating supply offset voltage	Note 1	200	
V <sub>HO</sub>	High side floating output voltage	V <sub>S</sub>	V <sub>B</sub>	
V <sub>CC</sub>	Low side fixed supply voltage	10	20	
V <sub>LO</sub>	Low side output voltage	0	V <sub>CC</sub>	
V <sub>IN</sub>	Logic input voltage (HIN & LIN)	COM	5.5	
T <sub>A</sub>	Ambient temperature	-40	125	

Note 1: Logic operational for V<sub>S</sub> of -4 to +200V. Logic state held for V<sub>S</sub> of -4V to -V<sub>BS</sub>.

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### Dynamic Electrical Characteristics

$V_{BIAS} (V_{CC}, V_{BS}) = 15V$ ,  $C_L = 1000 \text{ pF}$ ,  $T_A = 25^\circ\text{C}$  unless otherwise specified. Figure 1 shows the timing definitions.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$t_{on}$	Turn-on propagation delay	—	80	—	ns	$V_S = 0V$
$t_{off}$	Turn-off propagation delay	—	75	—		$V_S = 200V$
$t_r$	Turn-on rise time	—	35	50		
$t_f$	Turn-off fall time	—	20	35		
DM1	Turn-on delay matching   $t_{on} (H) - t_{on} (L)  $	—	5	20		
DM2	Turn-off delay matching   $t_{off} (H) - t_{off} (L)  $	—	5	20		

### Static Electrical Characteristics

$V_{BIAS} (V_{CC}, V_{BS}) = 15V$ , and  $T_A = 25^\circ\text{C}$  unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to COM and are applicable to all logic input leads: HIN and LIN. The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

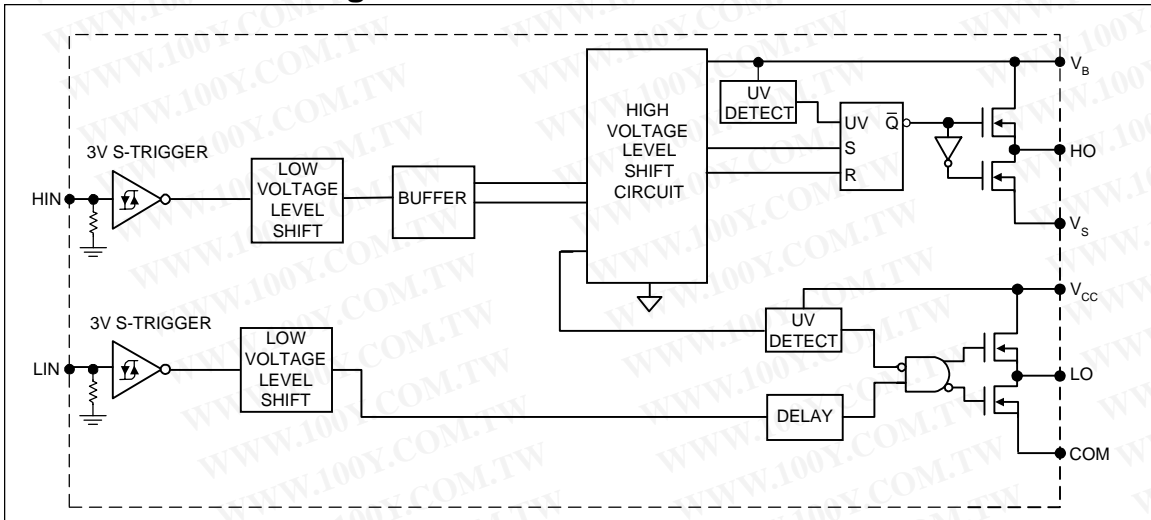
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$V_{IH}$	Logic "1" input voltage	2.2	—	—	V	$V_{CC} = 10V - 20V$
$V_{IL}$	Logic "0" input voltage	—	—	0.7		
$V_{OH}$	High level output voltage, $V_{BIAS} - V_O$	—	—	2.0		$I_O = 0A$
$V_{OL}$	Low level output voltage, $V_O$	—	—	0.2		20mA
$I_{LK}$	Offset supply leakage current	—	—	50	$\mu A$	$V_B = V_S = 200V$
$I_{QBS}$	Quiescent $V_{BS}$ supply current	—	90	210		$V_{IN} = 0V \text{ or } 3.3V$
$I_{QCC}$	Quiescent $V_{CC}$ supply current	—	140	230		$V_{IN} = 0V \text{ or } 3.3V$
$I_{IN+}$	Logic "1" input bias current	—	7.0	20		$V_{IN} = 3.3V$
$I_{IN-}$	Logic "0" input bias current	—	—	1.0		$V_{IN} = 0V$
$V_{BSUV+}$	$V_{BS}$ supply undervoltage positive going threshold	8.2	9.0	9.8	V	
$V_{BSUV-}$	$V_{BS}$ supply undervoltage negative going threshold	7.4	8.2	9.0		
$V_{CCUV+}$	$V_{CC}$ supply undervoltage positive going threshold	8.2	9.0	9.8		
$V_{CCUV-}$	$V_{CC}$ supply undervoltage negative going threshold	7.4	8.2	9.0		
$I_{O+}$	Output high short circuit pulsed current	—	1.0	—	A	$V_O = 0V$ , $PW \leq 10 \mu s$
$I_{O-}$	Output low short circuit pulsed current	—	1.0	—		$V_O = 15V$ , $PW \leq 10 \mu s$

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## Functional Block Diagram



## Lead Definitions

Symbol	Description
HIN	Logic input for high side gate driver output (HO), in phase
LIN	Logic input for low side gate driver output (LO), in phase
V <sub>B</sub>	High side floating supply
HO	High side gate drive output
V <sub>S</sub>	High side floating supply return
V <sub>CC</sub>	Low side supply
LO	Low side gate drive output
COM	Low side return

## Lead Assignments

<p>8-Lead PDIP</p> <p><b>IR2011</b></p>	<p>8-Lead SOIC also available LEAD-FREE (PbF)</p> <p><b>IR2011S</b></p>
<b>Part Number</b>	

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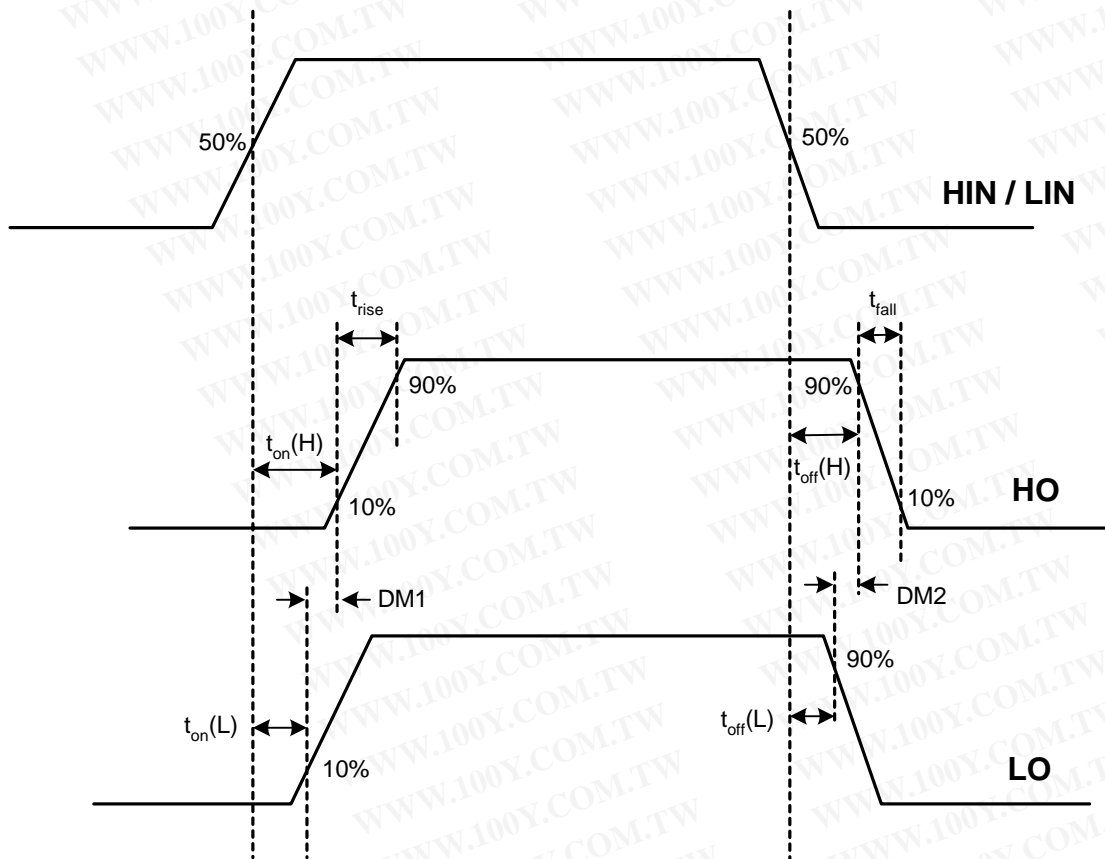
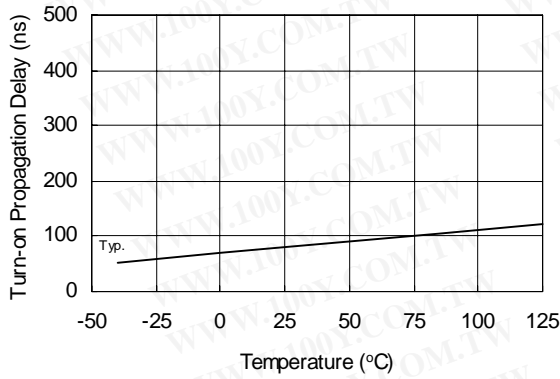


Figure 1. Timing Diagram

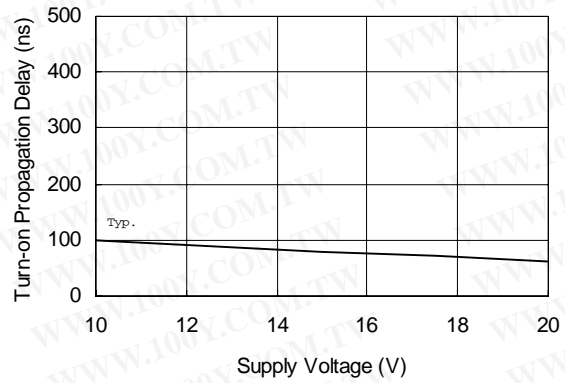
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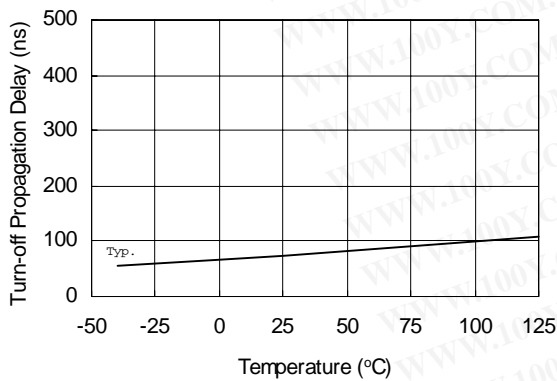
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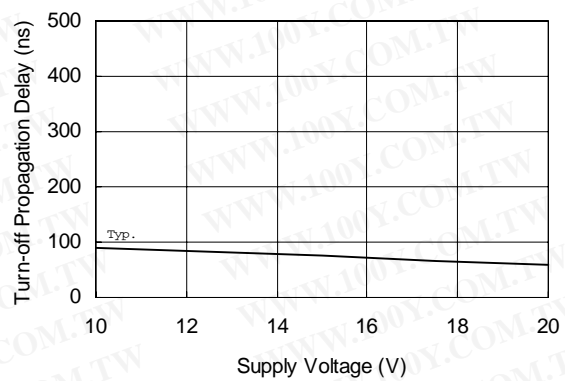
**Figure 2A. Turn-on Propagation Delay vs. Temperature**



**Figure 2B. Turn-on Propagation Delay vs. Supply Voltage**



**Figure 3A. Turn-off Propagation Delay vs. Temperature**



**Figure 3B. Turn-off Propagation Delay vs. Supply Voltage**

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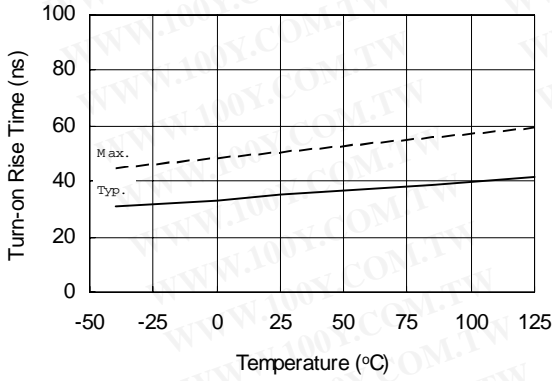


Figure 4A. Turn-on Rise Time vs. Temperature

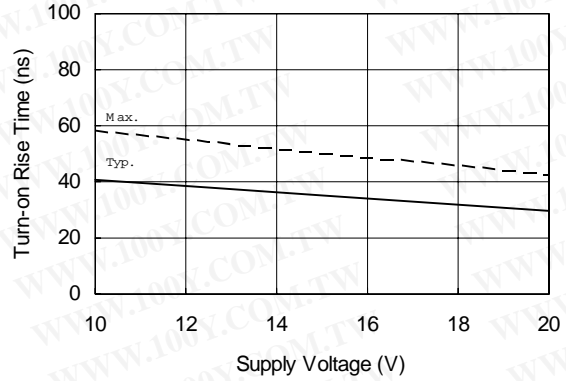


Figure 4B. Turn-on Rise Time vs. Supply Voltage

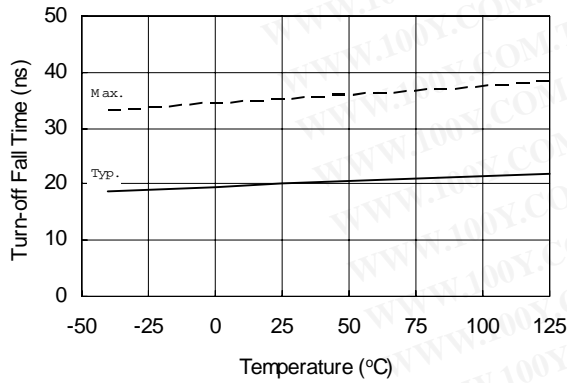


Figure 5A. Turn-off Fall Time vs. Temperature

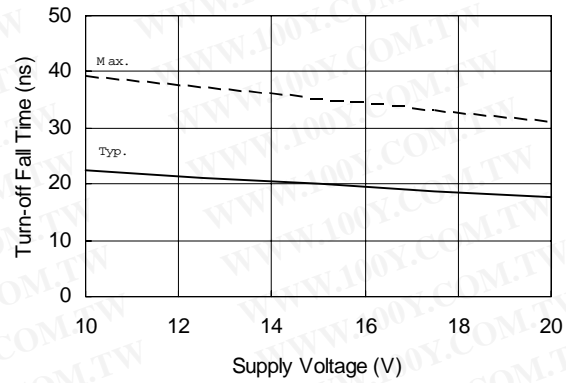
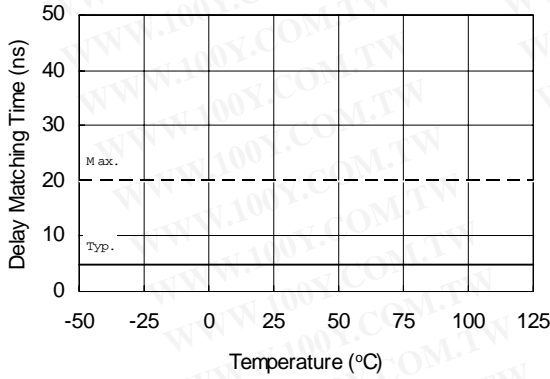


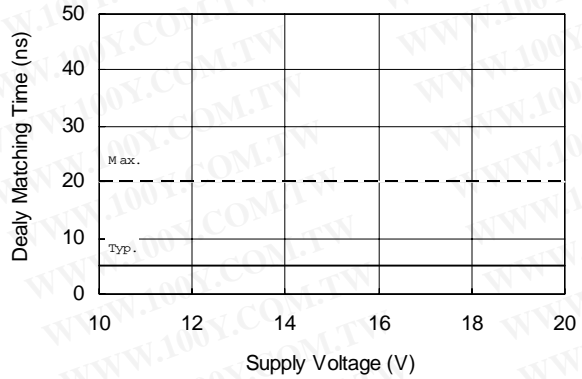
Figure 5B. Turn-off Fall Time vs. Supply Voltage

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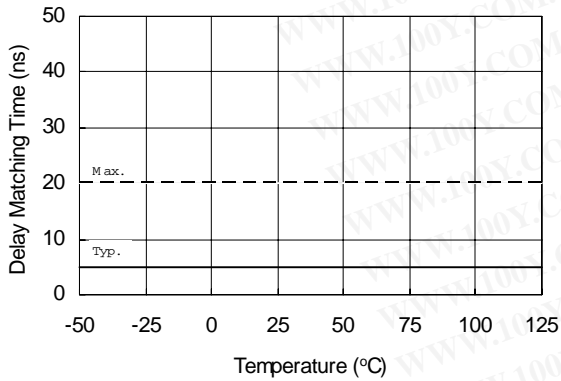
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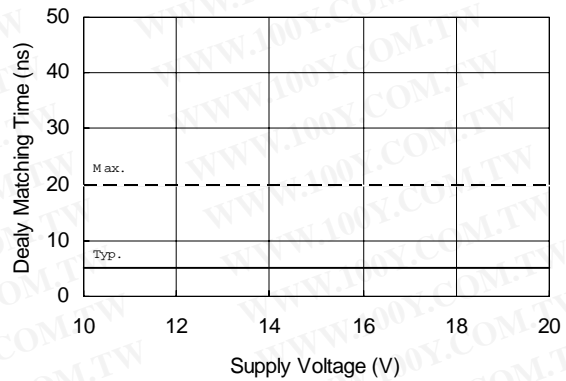
**Figure 6A. Turn-on Delay Matching Time vs. Temperature**



**Figure 6B. Turn-on Delay Matching Time vs. Supply Voltage**



**Figure 7A. Turn-off Delay Matching Time vs. Temperature**

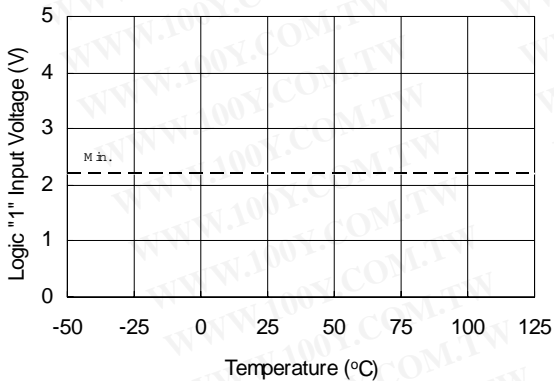


**Figure 7B. Turn-off Delay Matching Time vs. Supply Voltage**

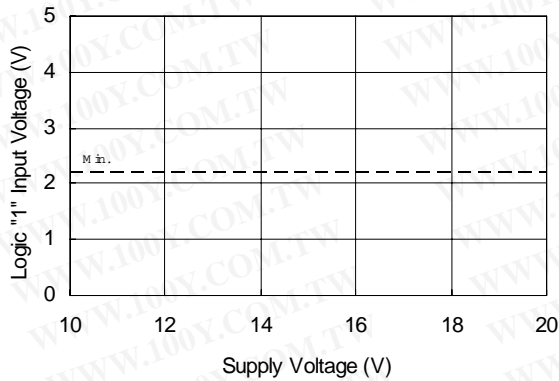
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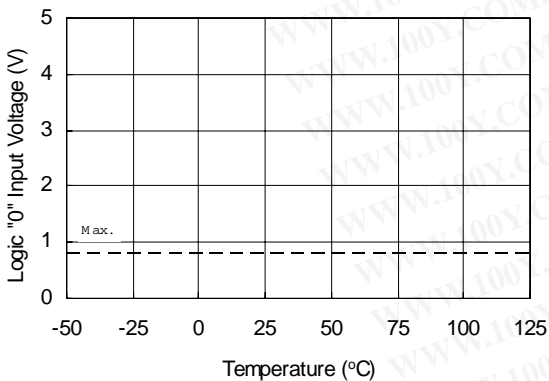
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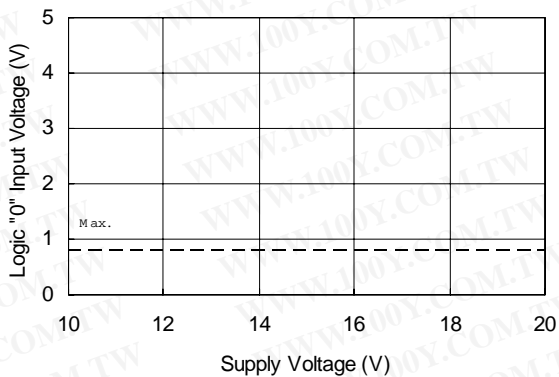
**Figure 8A. Logic "1" Input Voltage vs. Temperature**



**Figure 8B. Logic "1" Input Voltage vs. Supply Voltage**



**Figure 9A. Logic "0" Input Voltage vs. Temperature**



**Figure 9B. Logic "0" Input Voltage vs. Supply Voltage**

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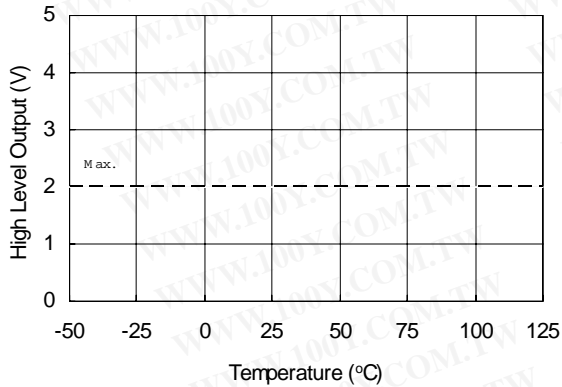


Figure 10A. High Level Output vs. Temperature

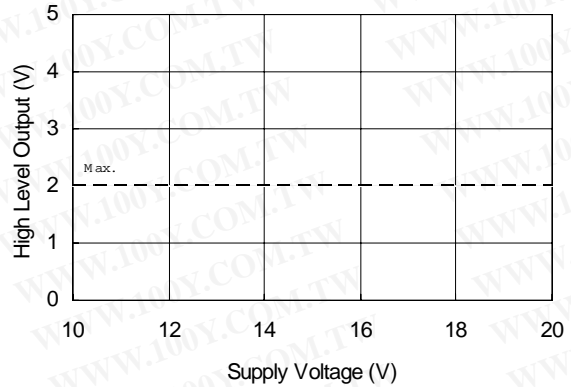


Figure 10B. High Level Output vs. Supply Voltage

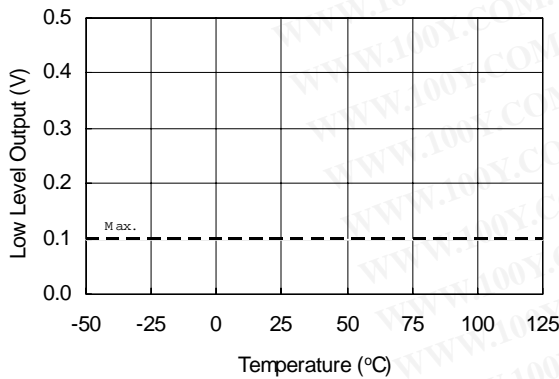


Figure 11A. Low Level Output vs. Temperature

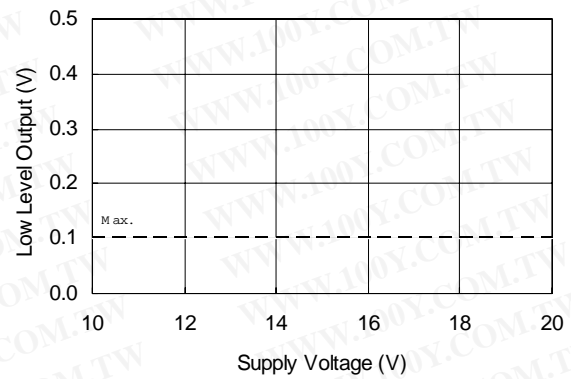
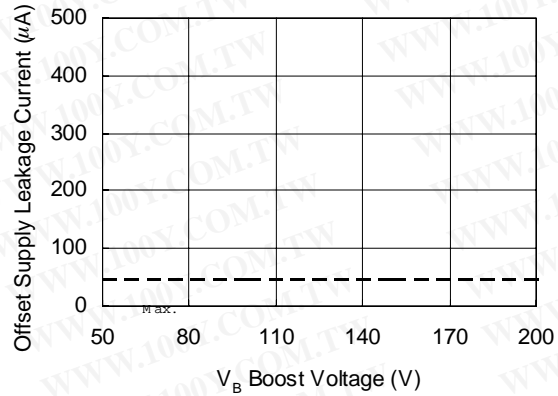
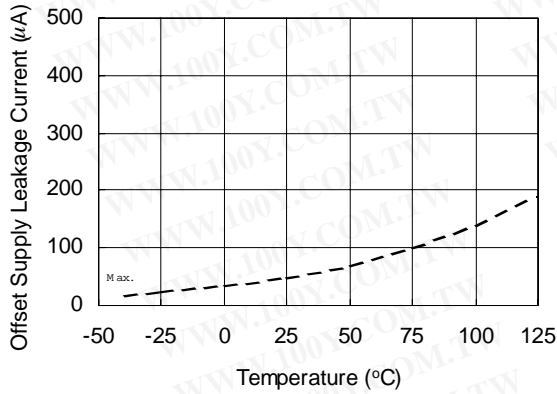


Figure 11B. Low Level Output vs. Supply Voltage

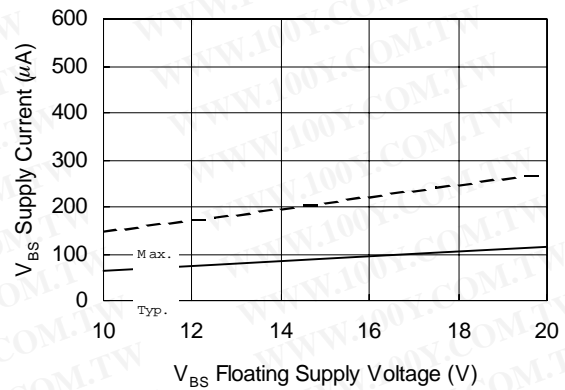
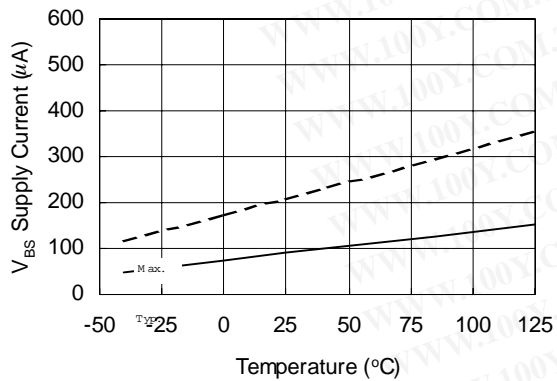
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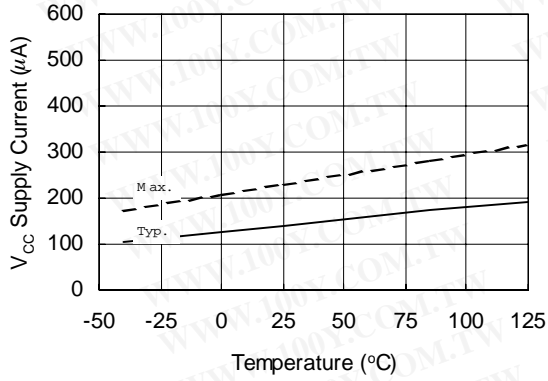
**Figure 12A. Offset Supply Leakage Current vs. Temperature**



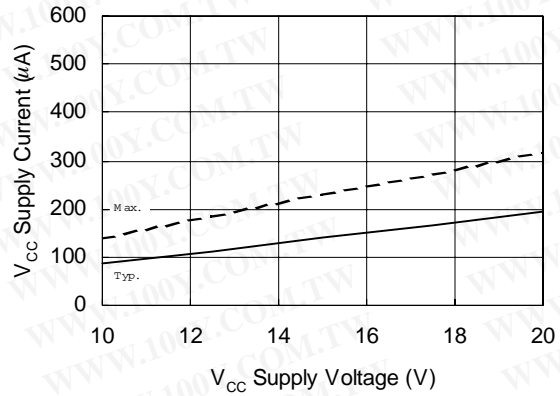
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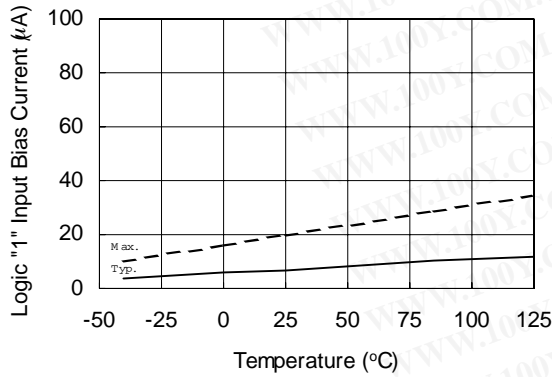
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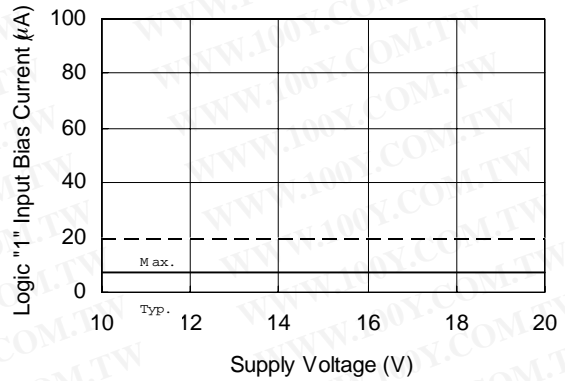
**Figure 14A. V<sub>CC</sub> Supply Current vs. Temperature**



**Figure 14B. V<sub>CC</sub> Supply Current vs. V<sub>CC</sub> Supply Voltage**



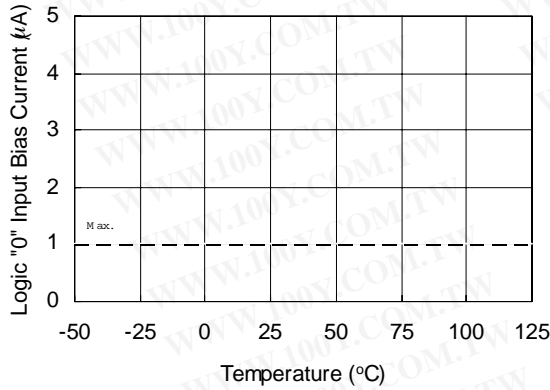
**Figure 15A. Logic "1" Input Bias Current vs. Temperature**



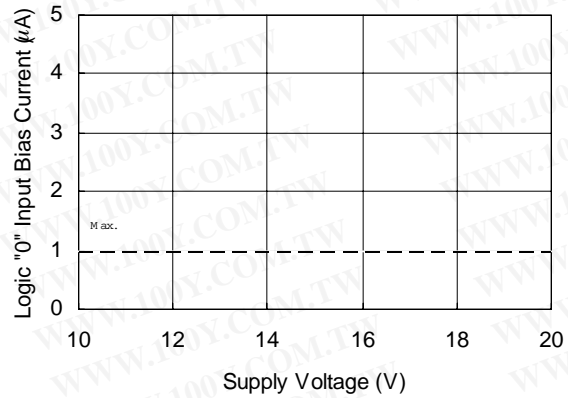
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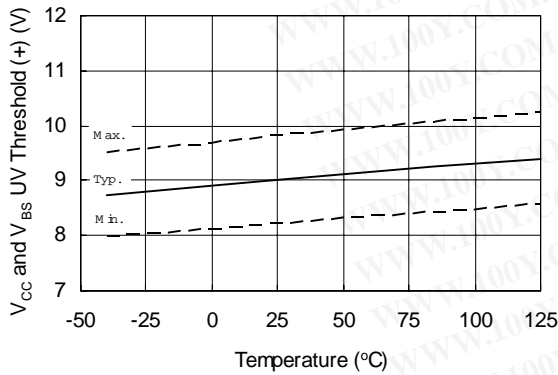
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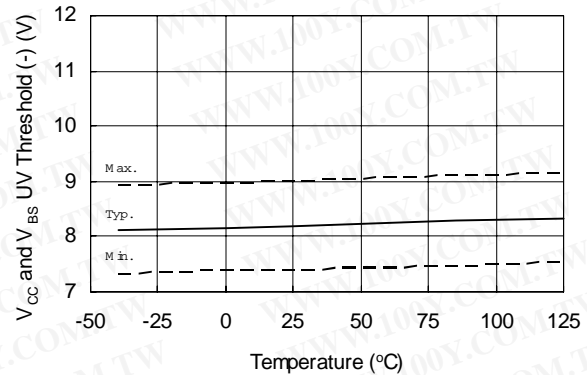
**Figure 16A. Logic "0" Input Bias Current vs. Temperature**



**Figure 16B. Logic "0" Input Bias Current vs. Supply Voltage**



**Figure 17.  $V_{CC}$  and  $V_{BS}$  Undervoltage Threshold (+) vs. Temperature**

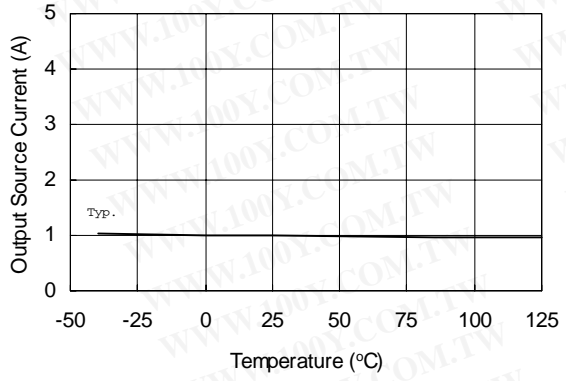


**Figure 18.  $V_{CC}$  and  $V_{BS}$  Undervoltage Threshold (-) vs. Temperature**

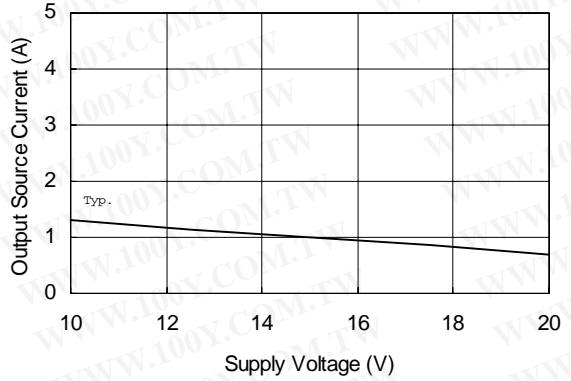
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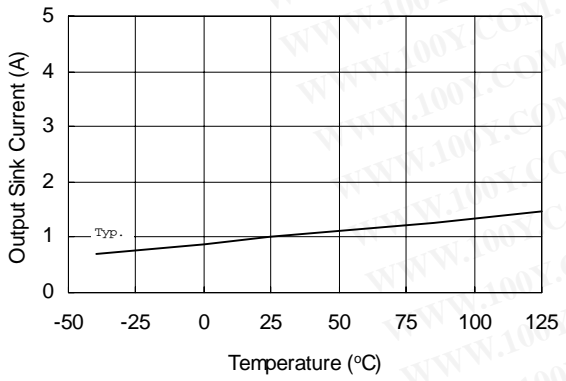
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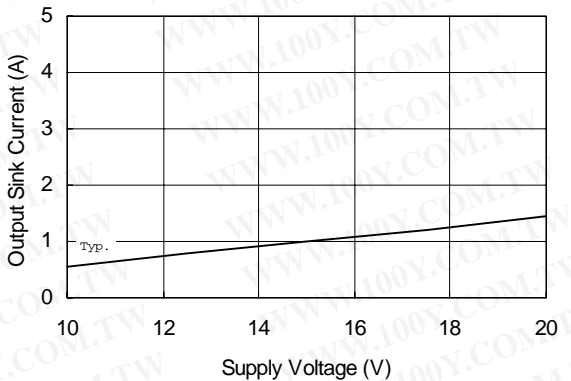
**Figure 19A. Output Source Current vs. Temperature**



**Figure 19B. Output Source Current vs. Supply Voltage**



**Figure 20A. Output Sink Current vs. Temperature**



**Figure 20B. Output Sink Current vs. Supply Voltage**

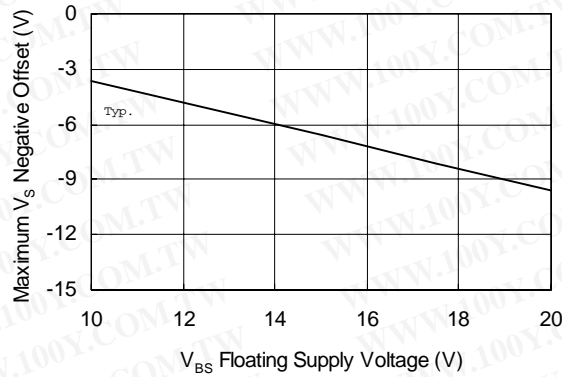


Figure 21. Maximum V<sub>s</sub> Negative Offset vs. V<sub>BS</sub> Floating Supply Voltage

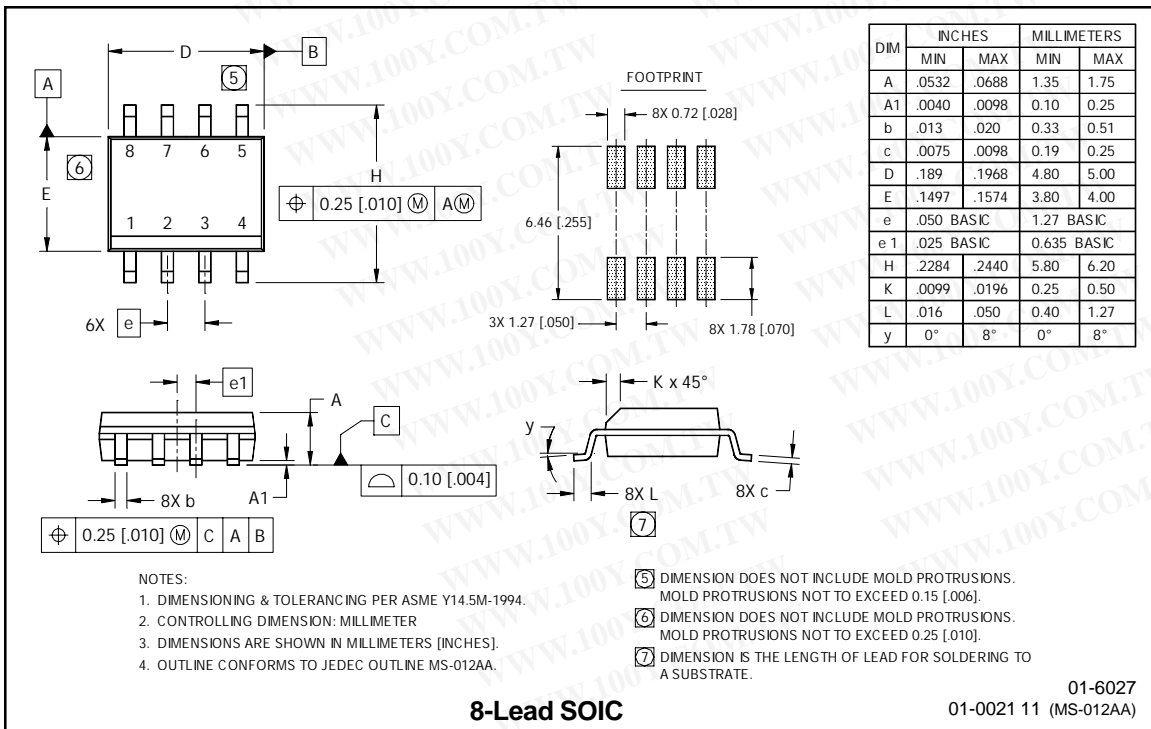
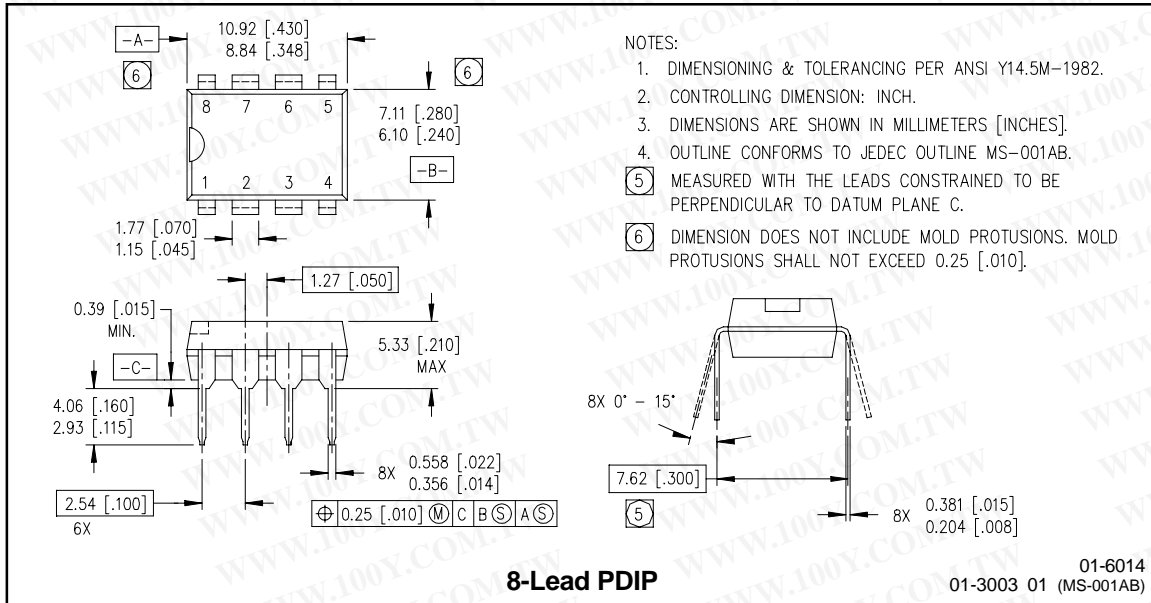
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# IR2011(S) & (PbF)

International  
**IR** Rectifier

## Case outlines

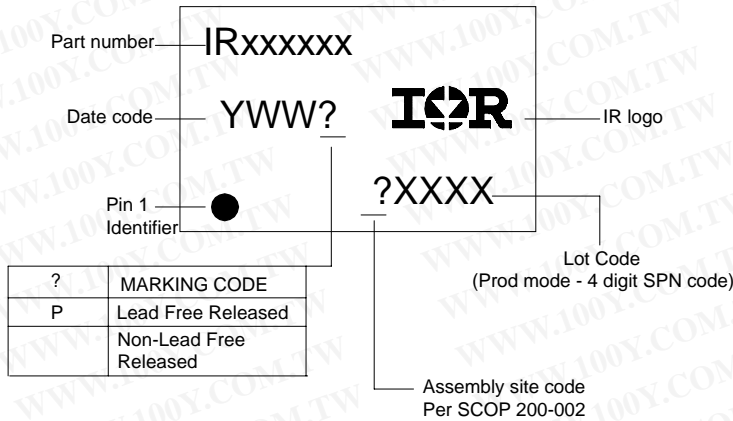


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 Http://www.100y.com.tw

International  
**IR** Rectifier

## IR2011(S) & (PbF)

### LEADFREE PART MARKING INFORMATION



### ORDER INFORMATION

#### Basic Part (Non-Lead Free)

8-Lead PDIP IR2011 order IR2011  
 8-Lead SOIC IR2011S order IR2011S

#### Leadfree Part

8-Lead PDIP IR2011 Not available  
 8-Lead SOIC IR2011S order IR2011SPbF

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**IR** Rectifier

**This product has been designed and qualified for the industrial market.**  
**Qualification Standards can be found on IR's Web Site** <http://www.irf.com/>.

Data and specifications subject to change without notice

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